



32K x 32 CacheRAM™
3.3V Synchronous SRAM
Burst Counter
Single Cycle Deselect

IDT71V432

Features

- ◆ 32K x 32 memory configuration
- ◆ Supports high-performance system speed:
Commercial and Industrial:
 - 5ns Clock-to-Data Access (100MHz)
 - 6ns Clock-to-Data Access (83MHz)
 - 7ns Clock-to-Data Access (66MHz)
- ◆ Single-cycle deselect functionality (Compatible with Micron Part # MT58LC32K32D7LG-XX)
- ◆ LBO input selects interleaved or linear burst mode
- ◆ Self-timed write cycle with global write control (**GW**), byte write enable (**BWE**), and byte writes (**BWx**)
- ◆ Power down controlled by ZZ input
- ◆ Operates with a single 3.3V power supply (+10/-5%)
- ◆ Packaged in a JEDEC Standard 100-pin rectangular plastic thin quad flatpack (TQFP).

Description

The IDT71V432 is a 3.3V high-speed 1,048,576-bit CacheRAM organized as 32K x 32 with full support of the Pentium™ and PowerPC™

processor interfaces. The pipelined burst architecture provides cost-effective 3-1-1-1 secondary cache performance for processors up to 100 MHz.

The IDT71V432 CacheRAM contains write, data, address, and control registers. Internal logic allows the CacheRAM to generate a self-timed write based upon a decision which can be left until the extreme end of the write cycle.

The burst mode feature offers the highest level of performance to the system designer, as the IDT71V432 can provide four cycles of data for a single address presented to the CacheRAM. An internal burst address counter accepts the first cycle address from the processor, initiating the access sequence. The first cycle of output data will be pipelined for one cycle before it is available on the next rising clock edge. If burst mode operation is selected (**ADV**=LOW), the subsequent three cycles of output data will be available to the user on the next three rising clock edges. The order of these three addresses will be defined by the internal burst counter and the **LBO** input pin.

The IDT71V432 CacheRAM utilizes IDT's high-performance, high-volume 3.3V CMOS process, and is packaged in a JEDEC Standard 14mm x 20mm 100-pin thin plastic quad flatpack (TQFP) for optimum board density in both desktop and notebook applications.

Pin Description Summary

| | | | |
|-------------------------------------------------------------------------------|-----------------------------------|--------|--------------|
| A0–A14 | Address Inputs | Input | Synchronous |
| \overline{CE} | Chip Enable | Input | Synchronous |
| CS ₀ , \overline{CS}_1 | Chips Selects | Input | Synchronous |
| \overline{OE} | Output Enable | Input | Asynchronous |
| \overline{GW} | Global Write Enable | Input | Synchronous |
| \overline{BWE} | Byte Write Enable | Input | Synchronous |
| \overline{BW}_1 , \overline{BW}_2 , \overline{BW}_3 , \overline{BW}_4 | Individual Byte Write Selects | Input | Synchronous |
| CLK | Clock | Input | N/A |
| \overline{ADV} | Burst Address Advance | Input | Synchronous |
| \overline{ADSC} | Address Status (Cache Controller) | Input | Synchronous |
| \overline{ADSP} | Address Status (Processor) | Input | Synchronous |
| \overline{LBO} | Linear / Interleaved Burst Order | Input | DC |
| ZZ | Sleep Mode | Input | Asynchronous |
| I/O ₀ –I/O ₃₁ | Data Input/Output | I/O | Synchronous |
| V _{DD} | 3.3V Power | Power | DC |
| V _{SS} | Ground | Ground | DC |

3104 tbl 01

CacheRAM is a trademark of Integrated Device Technology.
 Pentium processor is a trademark of Intel Corp.
 PowerPC is a trademark of International Business Machines, Inc.

AUGUST 2001

Pin Definitions⁽¹⁾

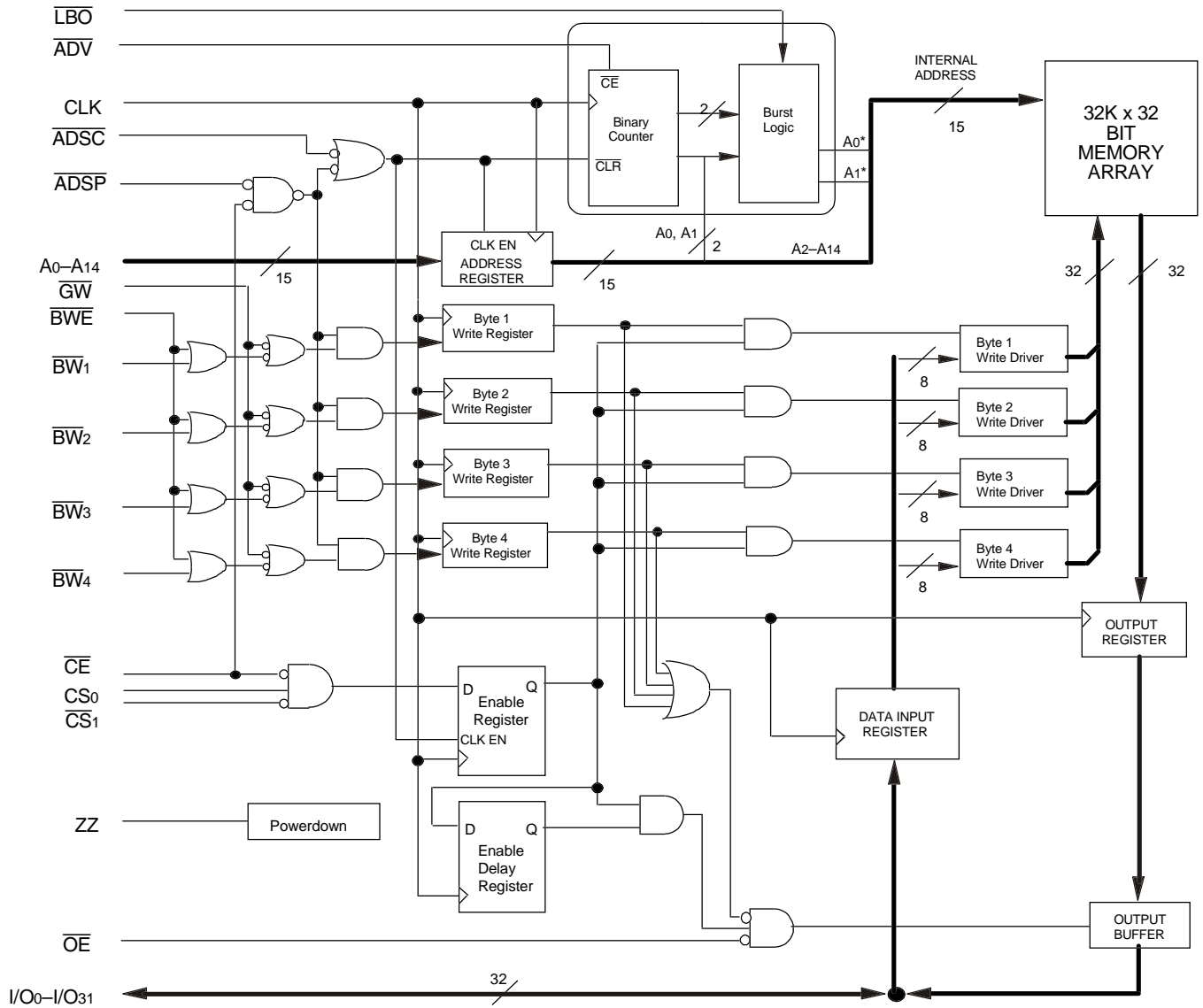
| Symbol | Pin Function | I/O | Active | Description |
|-------------------------------------|-----------------------------------|-----|--------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| A ₀ -A ₁₄ | Address Inputs | I | N/A | Synchronous Address inputs. The address register is triggered by a combination of the rising edge of CLK and \overline{ADSC} Low or \overline{ADSP} Low and \overline{CE} Low. |
| \overline{ADSC} | Address Status (Cache Controller) | I | LOW | Synchronous Address Status from Cache Controller. \overline{ADSC} is an active LOW input that is used to load the address registers with new addresses. \overline{ADSC} is NOT GATED by \overline{CE} . |
| \overline{ADSP} | Address Status (Processor) | I | LOW | Synchronous Address Status from Processor. \overline{ADSP} is an active LOW input that is used to load the address registers with new addresses. \overline{ADSP} is gated by \overline{CE} . |
| \overline{ADV} | Burst Address Advance | I | LOW | Synchronous Address Advance. \overline{ADV} is an active LOW input that is used to advance the internal burst counter, controlling burst access after the initial address is loaded. When this input is HIGH the burst counter is not incremented; that is, there is no address advance. |
| \overline{BWE} | Byte Write Enable | I | LOW | Synchronous byte write enable gates the byte write inputs $\overline{BW1}$ - $\overline{BW4}$. If \overline{BWE} is LOW at the rising edge of CLK then \overline{BWx} inputs are passed to the next stage in the circuit. A byte write can still be blocked if \overline{ADSP} is LOW at the rising edge of CLK. If \overline{ADSP} is HIGH and \overline{BWx} is LOW at the rising edge of CLK then data will be written to the SRAM. If \overline{BWE} is HIGH then the byte write inputs are blocked and only \overline{GW} can initiate a write cycle. |
| $\overline{BW1}$ - $\overline{BW4}$ | Individual Byte Write Enables | I | LOW | Synchronous byte write enables. $\overline{BW1}$ controls I/O(7:0), $\overline{BW2}$ controls I/O(15:8), etc. Any active byte write causes all outputs to be disabled. \overline{ADSP} LOW disables all byte writes. $\overline{BW1}$ - $\overline{BW4}$ must meet specified setup and hold times with respect to CLK. |
| \overline{CE} | Chip Enable | I | LOW | Synchronous chip enable. \overline{CE} is used with CS_0 and $\overline{CS_1}$ to enable the IDT71V432. \overline{CE} also gates \overline{ADSP} . |
| CLK | Clock | I | N/A | This is the clock input to the IDT71V432. All timing references for the device are made with respect to this input. |
| CS ₀ | Chip Select 0 | I | HIGH | Synchronous active HIGH chip select. CS ₀ is used with \overline{CE} and $\overline{CS_1}$ to enable the chip. |
| $\overline{CS_1}$ | Chip Select 1 | I | LOW | Synchronous active LOW chip select. $\overline{CS_1}$ is used with \overline{CE} and CS ₀ to enable the chip. |
| \overline{GW} | Global Write Enable | I | LOW | Synchronous global write enable. This input will write all four 8-bit data bytes when LOW on the rising edge of CLK. \overline{GW} supercedes individual byte write enables. |
| I/O ₀ -I/O ₃₁ | Data Input/Output | I/O | N/A | Synchronous data input/output (I/O) pins. Both the data input path and data output path are registered and triggered by the rising edge of CLK. |
| \overline{LBO} | Linear Burst Order | I | LOW | Asynchronous burst order selection DC input. When \overline{LBO} is HIGH the Interleaved (Intel) burst sequence is selected. When \overline{LBO} is LOW the Linear (PowerPC) burst sequence is selected. \overline{LBO} is a static DC input and must not change state while the device is operating. |
| \overline{OE} | Output Enable | I | LOW | Asynchronous output enable. When \overline{OE} is LOW the data output drivers are enabled on the I/O pins. \overline{OE} is gated internally by a delay circuit driven by \overline{CE} , CS ₀ , and $\overline{CS_1}$. In dual-bank mode, when the user is utilizing two banks of IDT71V432 and toggling back and forth between them using \overline{CE} , the internal delay circuit delays the \overline{OE} activation of the data output drivers by one cycle to prevent bus contention between the banks. When used in single bank mode \overline{CE} , CS ₀ , and $\overline{CS_1}$ are all tied active and there is no output enable delay. When \overline{OE} is HIGH the I/O pins are in a high-impedance state. |
| V _{DD} | Power Supply | N/A | N/A | 3.3V power supply inputs. |
| V _{SS} | Ground | N/A | N/A | Ground pins. |
| ZZ | Sleep Mode | I | HIGH | Asynchronous sleep mode input. ZZ HIGH will gate the CLK internally and power down the IDT71V432 to its lowest power consumption level. Data retention is guaranteed in Sleep Mode. |

NOTE:

- All synchronous inputs must meet specified setup and hold times with respect to CLK.

3104 tbl 02

Functional Block Diagram



3104 dw 01

Absolute Maximum Ratings⁽¹⁾

| Symbol | Rating | Value | Unit |
|----------------------------------|--------------------------------------|------------------------------|------|
| V _{TERM} ⁽²⁾ | Terminal Voltage with Respect to GND | -0.5 to +4.6 | V |
| V _{TERM} ⁽³⁾ | Terminal Voltage with Respect to GND | -0.5 to V _{DD} +0.5 | V |
| T _A | Operating Temperature | 0 to +70 | °C |
| T _{BIAS} | Temperature Under Bias | -55 to +125 | °C |
| T _{STG} | Storage Temperature | -55 to +125 | °C |
| P _T | Power Dissipation | 1.0 | W |
| I _{OUT} | DC Output Current | 50 | mA |

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NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{DD} and Input terminals only.
- I/O terminals.

Capacitance

(T_A = +25°C, f = 1.0MHz, TQFP package)

| Symbol | Parameter ⁽¹⁾ | Conditions | Max. | Unit |
|------------------|--------------------------|------------------------|------|------|
| C _{IN} | Input Capacitance | V _{IN} = 3dV | 6 | pF |
| C _{I/O} | I/O Capacitance | V _{OUT} = 3dV | 7 | pF |

3104 tbl 06

NOTE:

- This parameter is guaranteed by device characterization, but not production tested.

Recommended Operating Temperature and Supply Voltage

| Grade | Temperature | V _{SS} | V _{DD} |
|------------|----------------|-----------------|-----------------|
| Commercial | 0°C to +70°C | 0V | 3.3V+10/-5% |
| Industrial | -40°C to +85°C | 0V | 3.3V+10/-5% |

3104 tbl 03

Recommended DC Operating Conditions

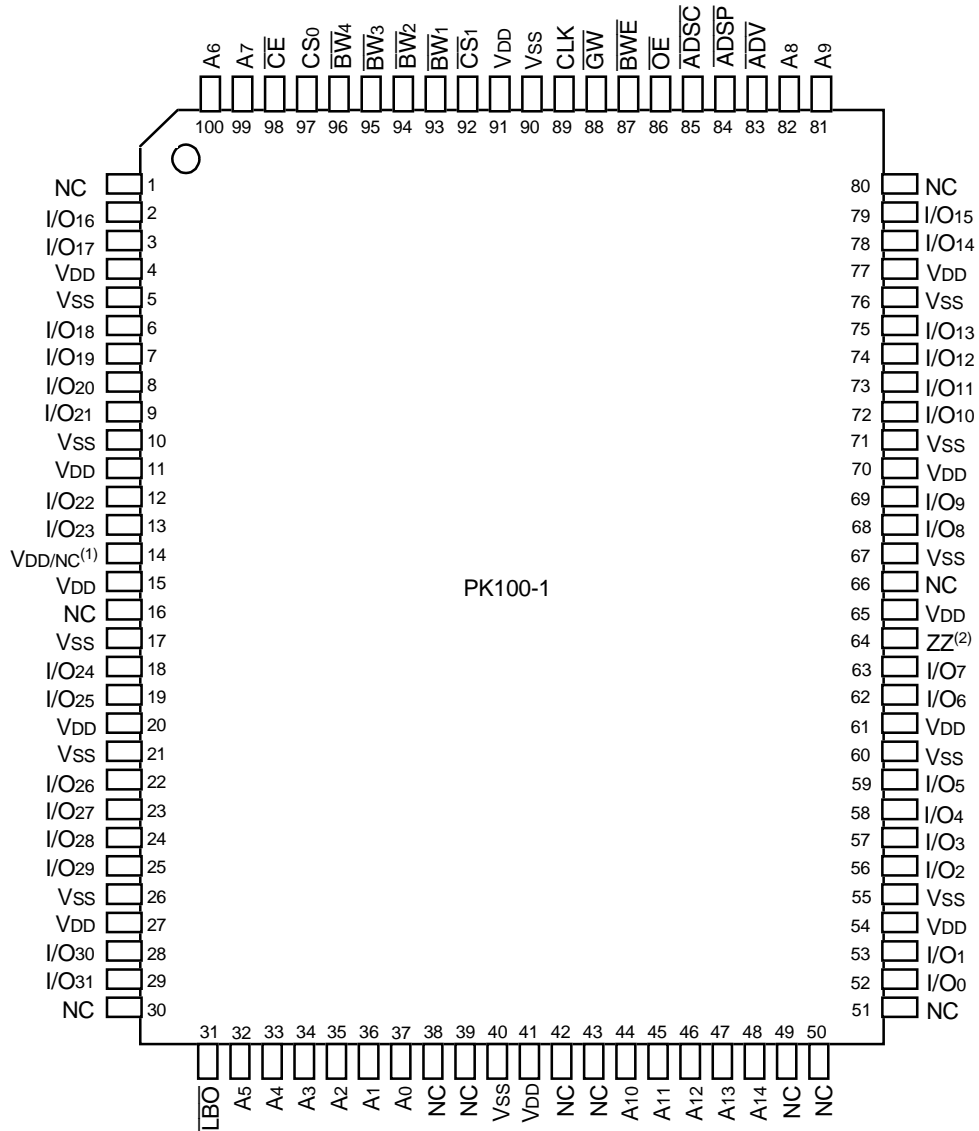
| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------------|-----------------------------|---------------------|------|----------------------|------|
| V _{DD} | Supply Voltage | 3.135 | 3.3 | 3.63 | V |
| V _{SS} | Ground | 0 | 0 | 0 | V |
| V _{IH} | Input High Voltage — Inputs | 2.0 | — | 4.6 ⁽²⁾ | V |
| V _{IH} | Input High Voltage — I/O | 2.0 | — | V _{DD} +0.3 | V |
| V _{IL} | Input Low Voltage | -0.5 ⁽¹⁾ | — | 0.8 | V |

3104 tbl 04

NOTES:

- V_{IL} (min) = -1.0V for pulse width less than tcyc/2, once per cycle.
- V_{IH} (max) = 6.0V for pulse width less than tcyc/2, once per cycle.

Pin Configuration



3104 drw 02

Top View TQFP

NOTES:

1. Pin 14 can either be directly connected to VDD or not connected.
2. Pin 64 can be left unconnected and the device will always remain in active mode.

Synchronous Truth Table^(1,2)

| Operation | Address Used | \overline{CE} | CS ₀ | \overline{CS}_1 | \overline{ADSP} | \overline{ADSC} | \overline{ADV} | \overline{GW} | \overline{BWE} | \overline{BW}_x | $\overline{OE}^{(3)}$ | CLK | I/O |
|------------------------------|--------------|-----------------|-----------------|-------------------|-------------------|-------------------|------------------|-----------------|------------------|-------------------|-----------------------|-----|------|
| Deselected Cycle, Power Down | None | H | X | X | X | L | X | X | X | X | X | ↑ | Hi-Z |
| Deselected Cycle, Power Down | None | L | X | H | L | X | X | X | X | X | X | ↑ | Hi-Z |
| Deselected Cycle, Power Down | None | L | L | X | L | X | X | X | X | X | X | ↑ | Hi-Z |
| Deselected Cycle, Power Down | None | L | X | H | X | L | X | X | X | X | X | ↑ | Hi-Z |
| Deselected Cycle, Power Down | None | L | L | X | X | L | X | X | X | X | X | ↑ | Hi-Z |
| Read Cycle, Begin Burst | External | L | H | L | L | X | X | X | X | X | L | ↑ | DOUT |
| Read Cycle, Begin Burst | External | L | H | L | L | X | X | X | X | X | H | ↑ | Hi-Z |
| Read Cycle, Begin Burst | External | L | H | L | H | L | X | H | H | X | L | ↑ | DOUT |
| Read Cycle, Begin Burst | External | L | H | L | H | L | X | H | L | H | L | ↑ | DOUT |
| Read Cycle, Begin Burst | External | L | H | L | H | L | X | H | L | H | H | ↑ | Hi-Z |
| Write Cycle, Begin Burst | External | L | H | L | H | L | X | H | L | L | X | ↑ | DIN |
| Write Cycle, Begin Burst | External | L | H | L | H | L | X | L | X | X | X | ↑ | DIN |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | H | X | L | ↑ | DOUT |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | H | X | H | ↑ | Hi-Z |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | X | H | L | ↑ | DOUT |
| Read Cycle, Continue Burst | Next | X | X | X | H | H | L | H | X | H | H | ↑ | Hi-Z |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | H | X | L | ↑ | DOUT |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | H | X | H | ↑ | Hi-Z |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | X | H | L | ↑ | DOUT |
| Read Cycle, Continue Burst | Next | H | X | X | X | H | L | H | X | H | H | ↑ | Hi-Z |
| Write Cycle, Continue Burst | Next | X | X | X | H | H | L | H | L | L | X | ↑ | DIN |
| Write Cycle, Continue Burst | Next | X | X | X | H | H | L | L | X | X | X | ↑ | DIN |
| Write Cycle, Continue Burst | Next | H | X | X | X | H | L | H | L | L | X | ↑ | DIN |
| Write Cycle, Continue Burst | Next | H | X | X | X | H | L | L | X | X | X | ↑ | DIN |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | H | X | L | ↑ | DOUT |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | H | X | H | ↑ | Hi-Z |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | X | H | L | ↑ | DOUT |
| Read Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | X | H | H | ↑ | Hi-Z |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | H | X | L | ↑ | DOUT |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | H | X | H | ↑ | Hi-Z |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | X | H | L | ↑ | DOUT |
| Read Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | X | H | H | ↑ | Hi-Z |
| Write Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | L | L | X | ↑ | DIN |
| Write Cycle, Suspend Burst | Current | X | X | X | H | H | H | L | X | X | X | ↑ | DIN |
| Write Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | L | L | X | ↑ | DIN |
| Write Cycle, Suspend Burst | Current | H | X | X | X | H | H | L | X | X | X | ↑ | DIN |

NOTES:

1. L = V_{IL}, H = V_{IH}, X = Don't Care.
2. ZZ = LOW for this table.
3. OE is an asynchronous input.

3104 tbl 07

Synchronous Write Function Truth Table⁽¹⁾

| Operation | \overline{GW} | \overline{BWE} | \overline{BW}_1 | \overline{BW}_2 | \overline{BW}_3 | \overline{BW}_4 |
|-----------------------------|-----------------|------------------|-------------------|-------------------|-------------------|-------------------|
| Read | H | H | X | X | X | X |
| Read | H | L | H | H | H | H |
| Write all Bytes | L | X | X | X | X | X |
| Write all Bytes | H | L | L | L | L | L |
| Write Byte 1 ⁽²⁾ | H | L | L | H | H | H |
| Write Byte 2 ⁽²⁾ | H | L | H | L | H | H |
| Write Byte 3 ⁽²⁾ | H | L | H | H | L | H |
| Write Byte 4 ⁽²⁾ | H | L | H | H | H | L |

3104 tbl 08

NOTES:

1. L = V_{IL} , H = V_{IH} , X = Don't Care.
2. Multiple bytes may be selected during the same cycle.

Asynchronous Truth Table⁽¹⁾

| Operation ⁽²⁾ | \overline{OE} | ZZ | I/O Status | Power |
|--------------------------|-----------------|----|----------------------------------------------------------|---------|
| Read | L | L | Data Out (I/O ₀ - I/O ₃₁) | Active |
| Read | H | L | High-Z | Active |
| Write | X | L | High-Z — Data In (I/O ₀ - I/O ₃₁) | Active |
| Deselected | X | L | High-Z | Standby |
| Sleep | X | H | High-Z | Sleep |

3104 tbl 09

NOTES:

1. L = V_{IL} , H = V_{IH} , X = Don't Care.
2. Synchronous function pins must be biased appropriately to satisfy operation requirements.

Interleaved Burst Sequence Table ($\overline{LBO}=V_{DD}$)

| | Sequence 1 | | Sequence 2 | | Sequence 3 | | Sequence 4 | |
|-------------------------------|------------|----|------------|----|------------|----|------------|----|
| | A1 | A0 | A1 | A0 | A1 | A0 | A1 | A0 |
| First Address | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 |
| Second Address | 0 | 1 | 0 | 0 | 1 | 1 | 1 | 0 |
| Third Address | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 |
| Fourth Address ⁽¹⁾ | 1 | 1 | 1 | 0 | 0 | 1 | 0 | 0 |

3104 tbl 10

NOTE:

1. Upon completion of the Burst sequence the counter wraps around to its initial state.

Linear Burst Sequence Table ($\overline{LBO}=V_{SS}$)

| | Sequence 1 | | Sequence 2 | | Sequence 3 | | Sequence 4 | |
|-------------------------------|------------|----|------------|----|------------|----|------------|----|
| | A1 | A0 | A1 | A0 | A1 | A0 | A1 | A0 |
| First Address | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 1 |
| Second Address | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 0 |
| Third Address | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 |
| Fourth Address ⁽¹⁾ | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 |

3104 tbl 11

NOTE:

1. Upon completion of the Burst sequence the counter wraps around to its initial state.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range ($V_{DD} = 3.3V \pm 10\%/5\%$, Commercial and Industrial Temperature Ranges)

| Symbol | Parameter | Test Conditions | Min. | Max. | Unit |
|------------|--------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------|------|------|---------|
| $ I_{LI} $ | Input Leakage Current | $V_{DD} = \text{Max.}, V_{IN} = 0V \text{ to } V_{DD}$ | — | 5 | μA |
| $ I_{LI} $ | ZZ and \overline{LBO} Input Leakage Current ⁽¹⁾ | $V_{DD} = \text{Max.}, V_{IN} = 0V \text{ to } V_{DD}$ | — | 30 | μA |
| $ I_{LO} $ | Output Leakage Current | $\overline{CE} \geq V_{IH}$ or $\overline{OE} \geq V_{IH}, V_{OUT} = 0V \text{ to } V_{DD}, V_{DD} = \text{Max.}$ | — | 5 | μA |
| V_{OL} | Output Low Voltage (I/O1–I/O31) | $I_{OL} = 5mA, V_{DD} = \text{Min.}$ | — | 0.4 | V |
| V_{OH} | Output High Voltage (I/O1–I/O31) | $I_{OH} = -5mA, V_{DD} = \text{Min.}$ | 2.4 | — | V |

3104 tbl 12

NOTE:

- The \overline{LBO} pin will be internally pulled to V_{DD} if it is not actively driven in the application and the ZZ pin will be internally pulled to V_{SS} if not actively driven.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range⁽¹⁾ ($V_{DD} = 3.3V \pm 10\%/5\%$, $V_{HD} = V_{DD} - 0.2V$, $V_{LD} = 0.2V$)

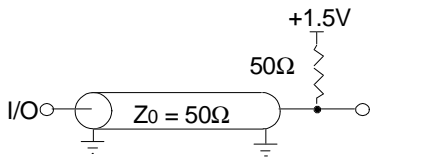
| Symbol | Parameter | Test Conditions | IDT71V432S5 | | IDT71V432S6 | | IDT71V432S7 | | Unit |
|-----------|--------------------------------------|-----------------------------------------------------------------------------------------------------------------|-------------|------|-------------|------|-------------|------|------|
| | | | Com'l. | Ind. | Com'l. | Ind. | Com'l. | Ind. | |
| I_{DD} | Operating Power Supply Current | Device Selected, Outputs Open, $V_{DD} = \text{Max.}, V_{IN} \geq V_{IH}$ or $\leq V_{IL}, f = f_{MAX}^{(2)}$ | 200 | 200 | 180 | 180 | 160 | 160 | mA |
| I_{SB} | Standby Power Supply Current | Device Deselected, Outputs Open, $V_{DD} = \text{Max.}, V_{IN} \geq V_{IH}$ or $\leq V_{IL}, f = f_{MAX}^{(2)}$ | 65 | 65 | 60 | 60 | 55 | 55 | mA |
| I_{SB1} | Full Standby Power Supply Current | Device Deselected, Outputs Open, $V_{DD} = \text{Max.}, V_{IN} \geq V_{HD}$ or $\leq V_{LD}, f = 0^{(2)}$ | 15 | 15 | 15 | 15 | 15 | 15 | mA |
| I_{ZZ} | Full Sleep Mode Power Supply Current | $ZZ \geq V_{HD}, V_{DD} = \text{Max.}$ | 10 | 10 | 10 | 10 | 10 | 10 | mA |

3104 tbl 13

NOTES:

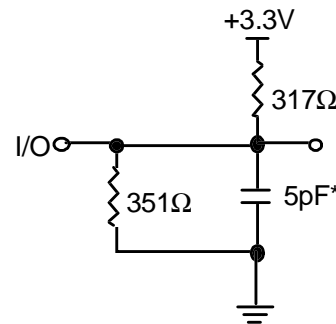
- All values are maximum guaranteed values.
- At $f = f_{MAX}$, inputs are cycling at the maximum frequency of read cycles of $1/t_{cyc}$ while $\overline{ADSC} = \text{LOW}$; $f=0$ means no input lines are changing.

AC Test Loads



3104 drw 03

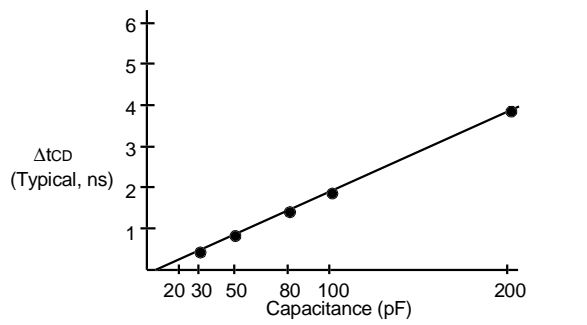
Figure 1. AC Test Load



* Including scope and jig capacitance.

3104 drw 04

Figure 2. AC Test Load (for t_{OHZ} , t_{CHZ} , t_{OLZ} , and t_{OC1})



3104 drw 05

Figure 3. Lumped Capacitive Load, Typical Derating

AC Test Conditions

| | |
|--------------------------------|---------------------|
| Input Pulse Levels | 0 to 3.0V |
| Input Rise/Fall Times | 2ns |
| Input Timing Reference Levels | 1.5V |
| Output Timing Reference Levels | 1.5V |
| AC Test Load | See Figures 1 and 2 |

3104 tbl 14

AC Electrical Characteristics (VDD = 3.3V +10/-5%, Commercial and Industrial Temperature Ranges)

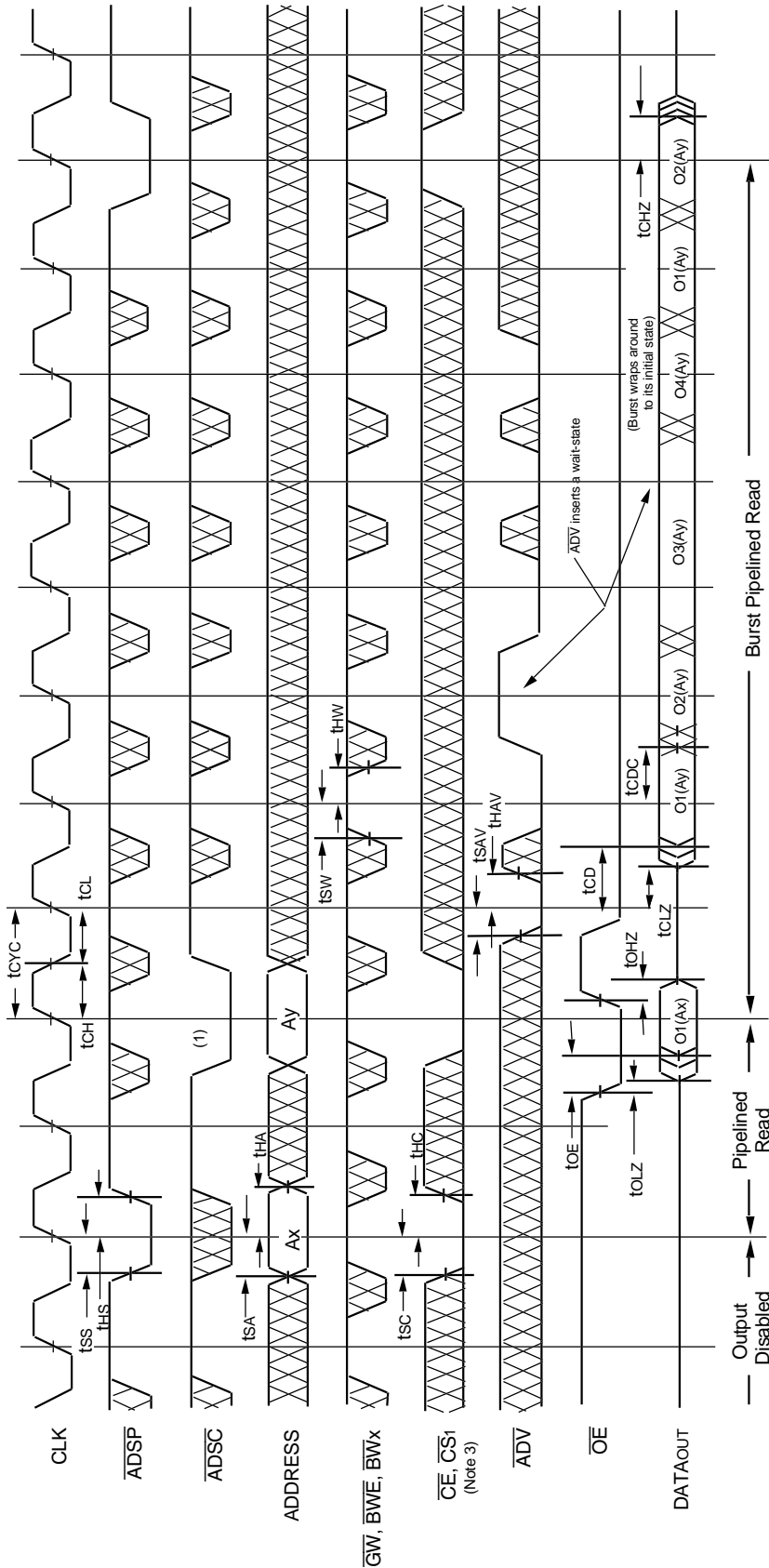
| Symbol | Parameter | 71V432S5 | | 71V432S6 | | 71V432S7 | | Unit |
|------------------------------------------------|-----------------------------------|----------|------|----------|------|----------|------|------|
| | | Min. | Max. | Min. | Max. | Min. | Max. | |
| CLOCK PARAMETERS | | | | | | | | |
| tcyc | Clock Cycle Time | 10 | — | 12 | — | 15 | — | ns |
| tch ⁽¹⁾ | Clock High Pulse Width | 4 | — | 4.5 | — | 5 | — | ns |
| tcl ⁽¹⁾ | Clock Low Pulse Width | 4 | — | 4.5 | — | 5 | — | ns |
| OUTPUT PARAMETERS | | | | | | | | |
| tcd | Clock High to Valid Data | — | 5 | — | 6 | — | 7 | ns |
| tcDC | Clock High to Data Change | 1.5 | — | 2 | — | 2 | — | ns |
| tclZ ⁽²⁾ | Clock High to Output Active | 0 | — | 0 | — | 0 | — | ns |
| tchZ ⁽²⁾ | Clock High to Data High-Z | 1.5 | 5 | 2 | 5 | 2 | 6 | ns |
| toE | Output Enable Access Time | — | 5 | — | 5 | — | 6 | ns |
| tolZ ⁽²⁾ | Output Enable Low to Data Active | 0 | — | 0 | — | 0 | — | ns |
| toHZ ⁽²⁾ | Output Enable High to Data High-Z | — | 4 | — | 5 | — | 6 | ns |
| SETUP TIMES | | | | | | | | |
| tSA | Address Setup Time | 2.5 | — | 2.5 | — | 2.5 | — | ns |
| tSS | Address Status Setup Time | 2.5 | — | 2.5 | — | 2.5 | — | ns |
| tSD | Data in Setup Time | 2.5 | — | 2.5 | — | 2.5 | — | ns |
| tSW | Write Setup Time | 2.5 | — | 2.5 | — | 2.5 | — | ns |
| tSAV | Address Advance Setup Time | 2.5 | — | 2.5 | — | 2.5 | — | ns |
| tSC | Chip Enable/Select Setup Time | 2.5 | — | 2.5 | — | 2.5 | — | ns |
| HOLD TIMES | | | | | | | | |
| tHA | Address Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| tHS | Address Status Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| tHD | Data In Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| tHW | Write Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| tHAV | Address Advance Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| tHC | Chip Enable/Select Hold Time | 0.5 | — | 0.5 | — | 0.5 | — | ns |
| SLEEP MODE AND CONFIGURATION PARAMETERS | | | | | | | | |
| tZZPW | ZZ Pulse Width | 100 | — | 100 | — | 100 | — | ns |
| tZZR ⁽³⁾ | ZZ Recovery Time | 100 | — | 100 | — | 100 | — | ns |
| tCFG ⁽⁴⁾ | Configuration Set-up Time | 40 | — | 50 | — | 50 | — | ns |

3104 tbl 15

NOTES:

1. Measured as HIGH above 2.0V and LOW below 0.8V.
2. Transition is measured ±200mV from steady-state.
3. Device must be deselected when powered-up from sleep mode.
4. tCFG is the minimum time required to configure the device based on the $\overline{\text{LBO}}$ input. $\overline{\text{LBO}}$ is a static input and must not change during normal operation.

Timing Waveform of Pipelined Read Cycle^(1,2)

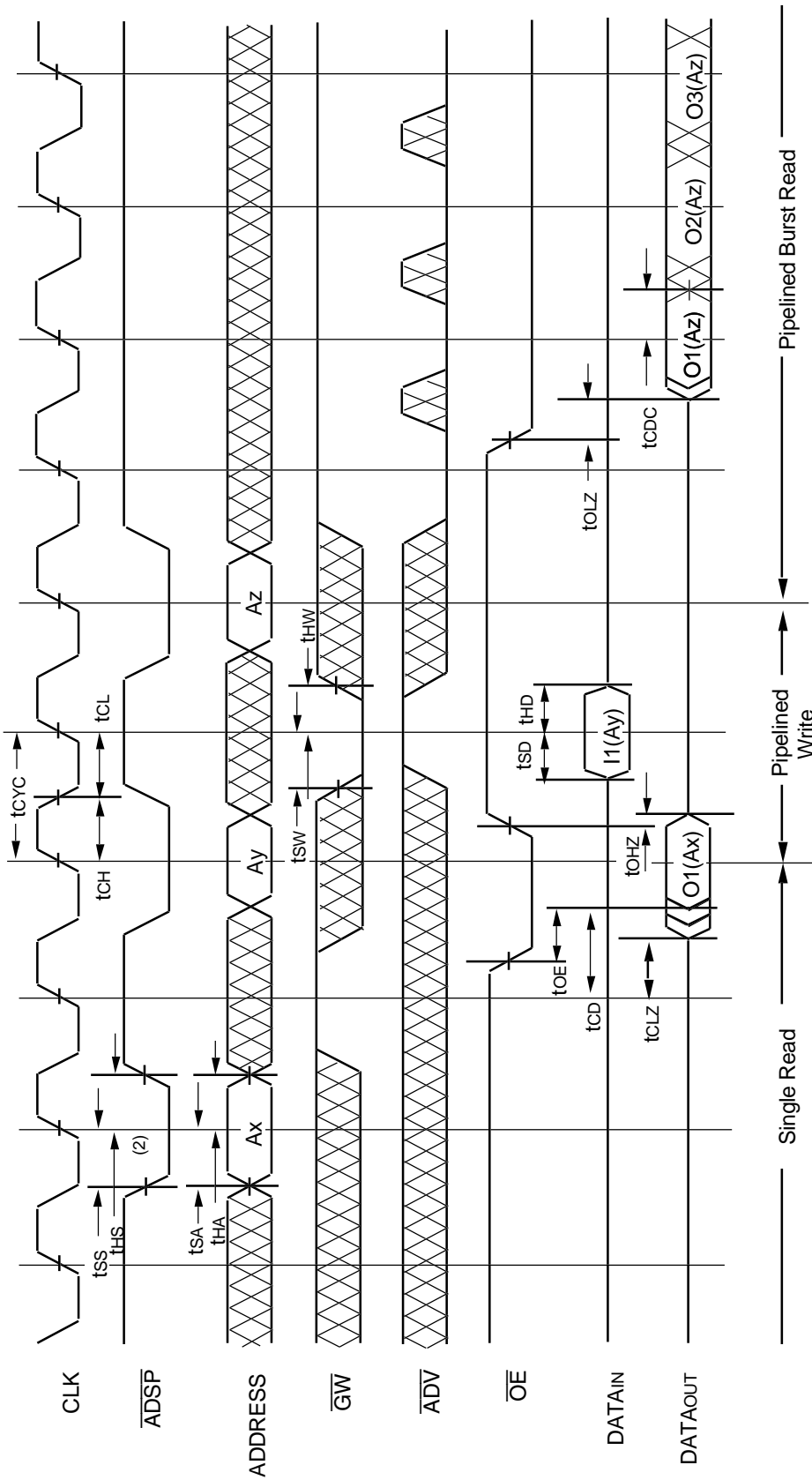


3104 drw 06

NOTES:

1. O1 (Ax) represents the first output from the external address Ax. O1 (Ay) represents the first output from the external address Ay. O2 (Ay) represents the next output data in the burst sequence of the base address Ay, etc. where Ax and Ay are advancing for the four word burst in the sequence defined by the state of the LBO input.
2. Zz input is LOW and LBO is Don't Care for this cycle.
3. CS0 limiting transitions are identical but inverted to the \overline{CE} and $\overline{CS1}$ signals. For example, when \overline{CE} and $\overline{CS1}$ are LOW on this waveform, CS0 is HIGH.

Timing Waveform of Combined Pipelined Read and Write Cycles^(1,2,3)

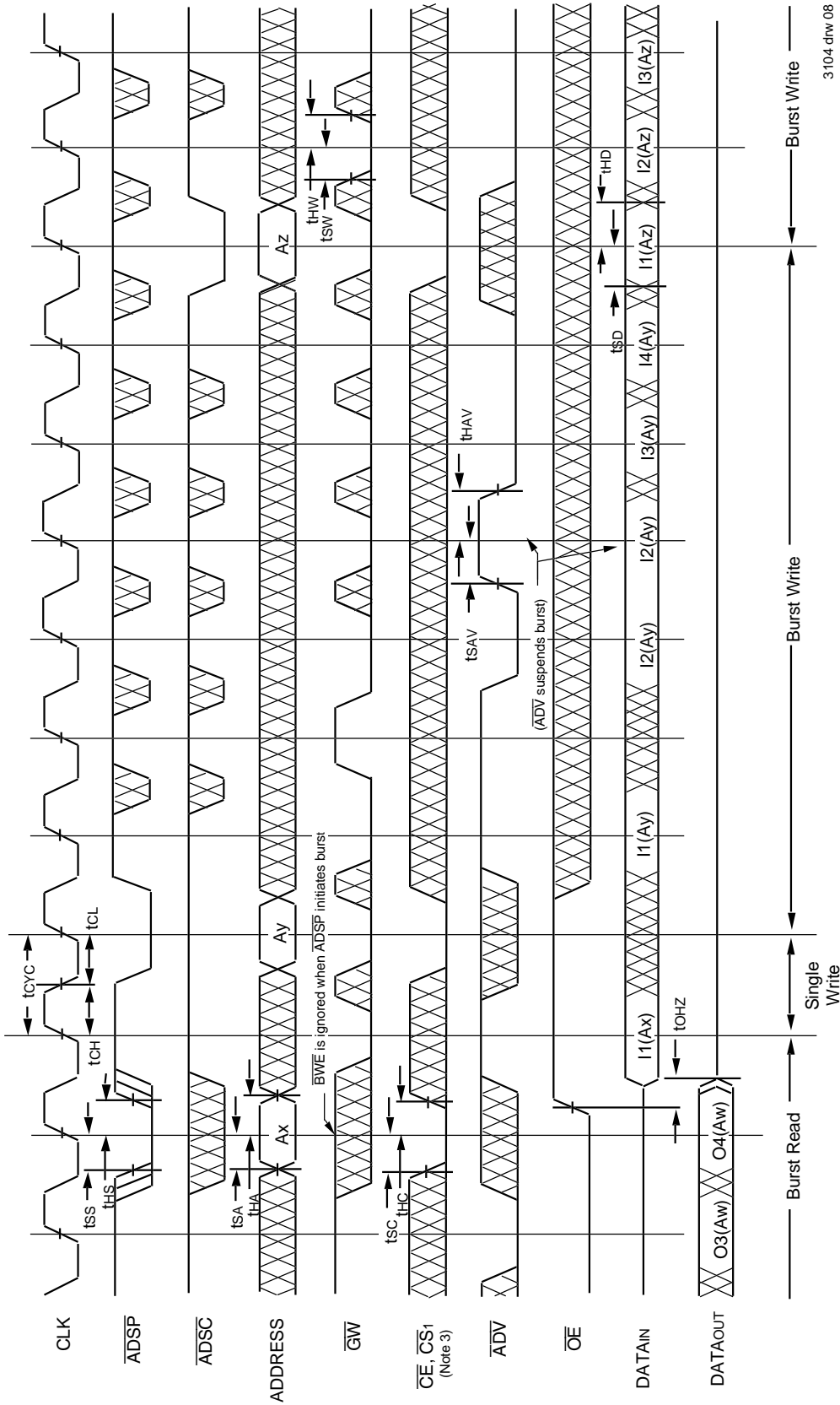


3104.drw.07

NOTES:

1. Device is selected through entire cycle: \overline{CE} and $\overline{CS1}$ are LOW, $\overline{CS0}$ is HIGH.
2. ZZ input is LOW and LBO is Don't Care for this cycle.
3. O1(Ax) represents the first output from the external address Ax. I1 (Ay) represents the first input from the external address Ay. O1(Az) represents the first output from the external address Az; O2(Az) represents the next output data in the burst sequence of the base address Az, etc. where A0 and A1 are advancing for the four word burst in the sequence defined by the state of the LBO input.

Timing Waveform of Write Cycle No. 1 — $\overline{\text{GW}}$ Controlled^(1,2,3)

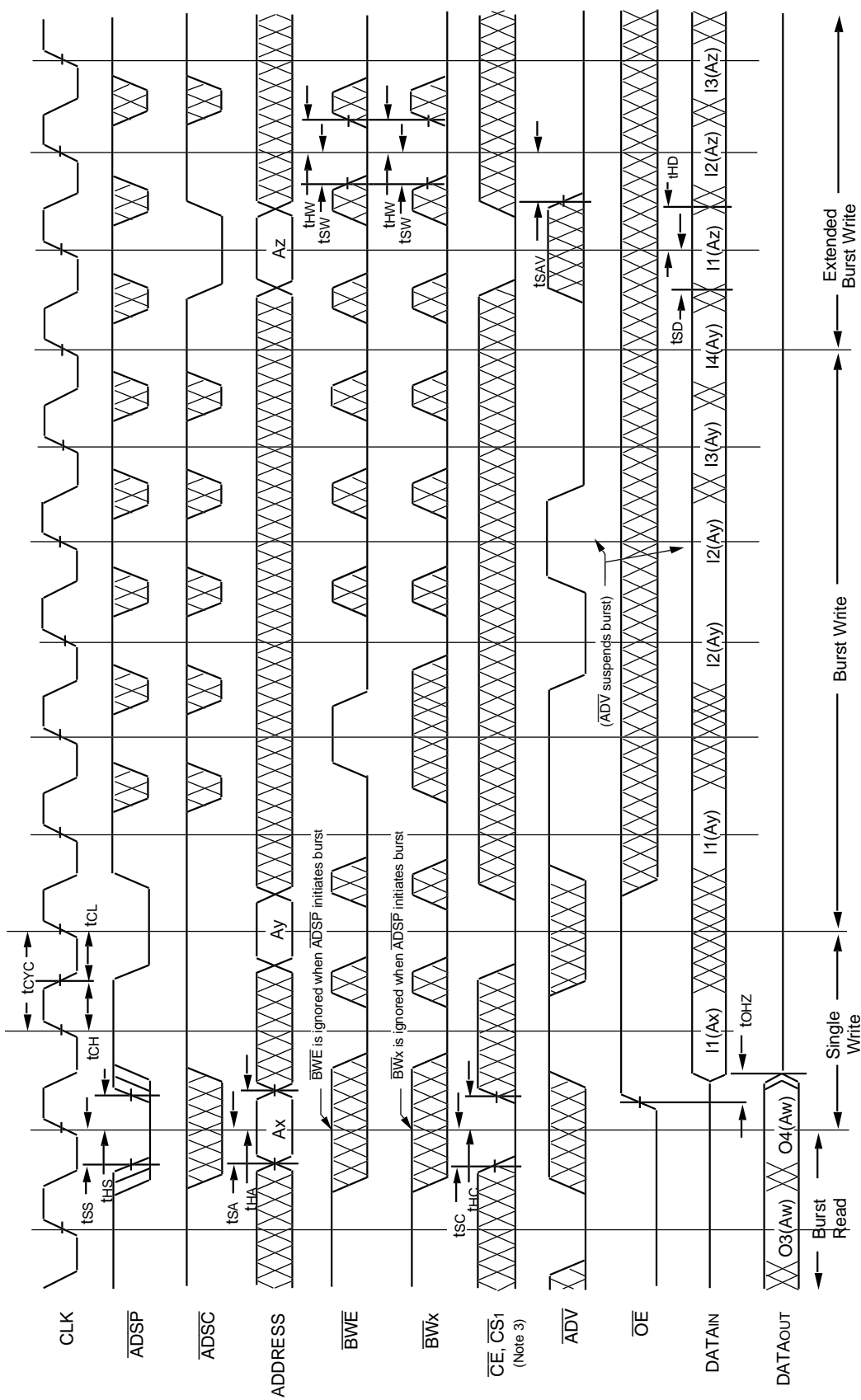


3104.dnw.08

NOTES:

1. Z input is LOW, $\overline{\text{BWE}}$ is HIGH, and $\overline{\text{LBO}}$ is Don't Care for this cycle.
2. O4(Aw) represents the final output data in the burst sequence of the base address Aw. I1(Ay) represents the first input from the external address. I1(Ay) represents the first input from the external address. Ay: I2(Ay) represents the next input data in the burst sequence of the base address Ay, etc. where A0 and A1 are advancing for the four word burst in the sequence defined by the state of the $\overline{\text{LBO}}$ input. In the case of input I2(Ay) this data is valid for two cycles because ADV is high and has suspended the burst.
3. CS0 timing transitions are identical but inverted to the $\overline{\text{CE}}$ and $\overline{\text{CS}}_1$ signals. For example, when $\overline{\text{CE}}$ and $\overline{\text{CS}}_1$ are LOW on this waveform, CS0 is HIGH.

Timing Waveform of Write Cycle No. 2 — Byte Controlled^(1,2,3)

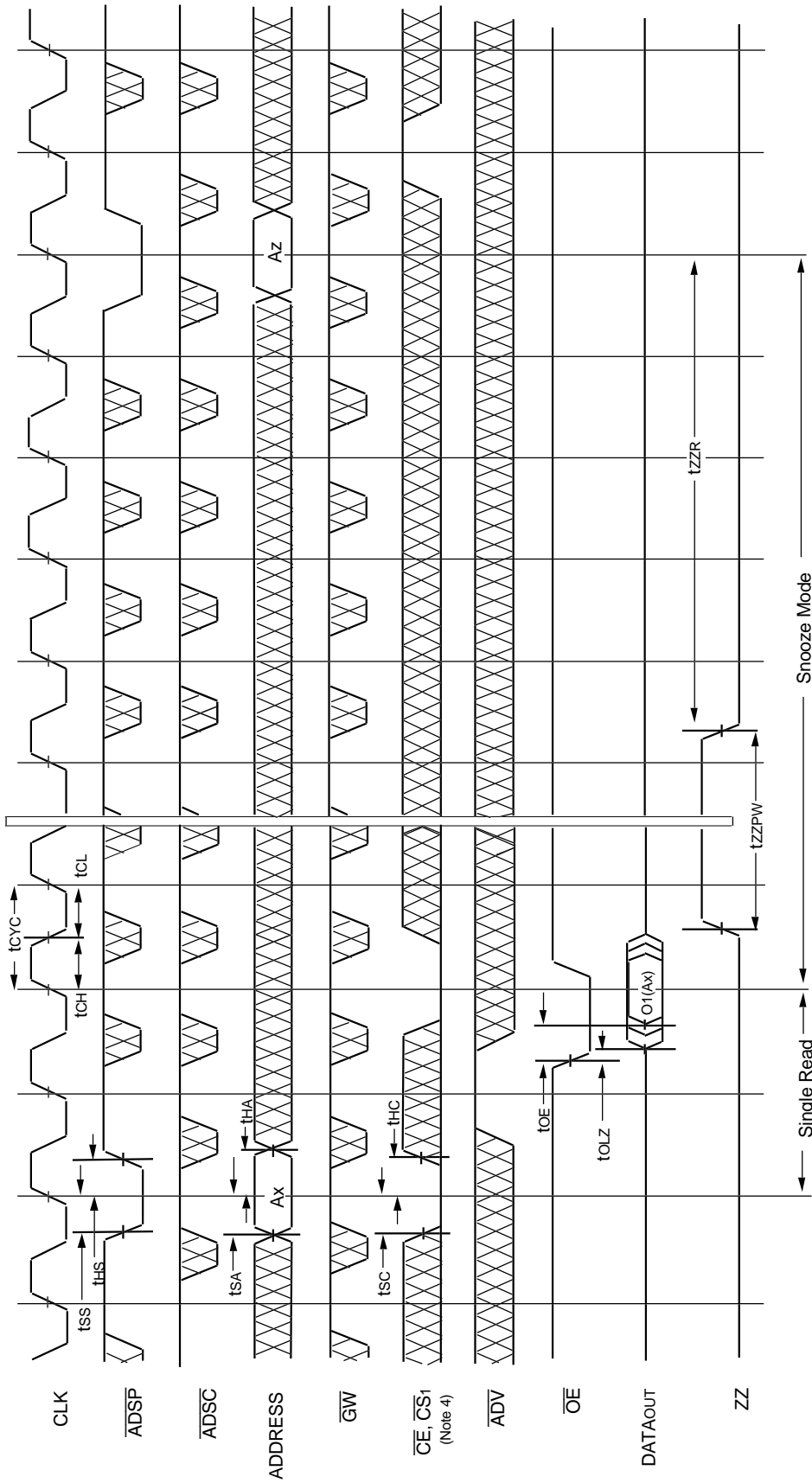


3104.drw.09

NOTES:

1. Z_Z input is LOW, $\overline{G\overline{W}}$ is HIGH, and $\overline{L\overline{B\overline{O}}}$ is Don't Care for this cycle.
2. O4(Aw) represents the final output data in the burst sequence of the base address Aw. I1(Ax) represents the first input from the external address Ay. I2(Ay) represents the next input data in the burst sequence of the base address Ay, etc. where A₀ and A₁ are advancing for the four word burst in the sequence defined by the state of the $\overline{L\overline{B\overline{O}}}$ input. In the case of input I2(Ay) this data is valid for two cycles because ADV is high and has suspended the burst.
3. CS₀ limiting transitions are identical but inverted to the $\overline{C\overline{E}}$ and $\overline{C\overline{S1}}$ signals. For example, when $\overline{C\overline{E}}$ and $\overline{C\overline{S1}}$ are LOW on this waveform, CS₀ is HIGH.

Timing Waveform of Sleep (ZZ) and Power-Down Modes^(1,2,3)

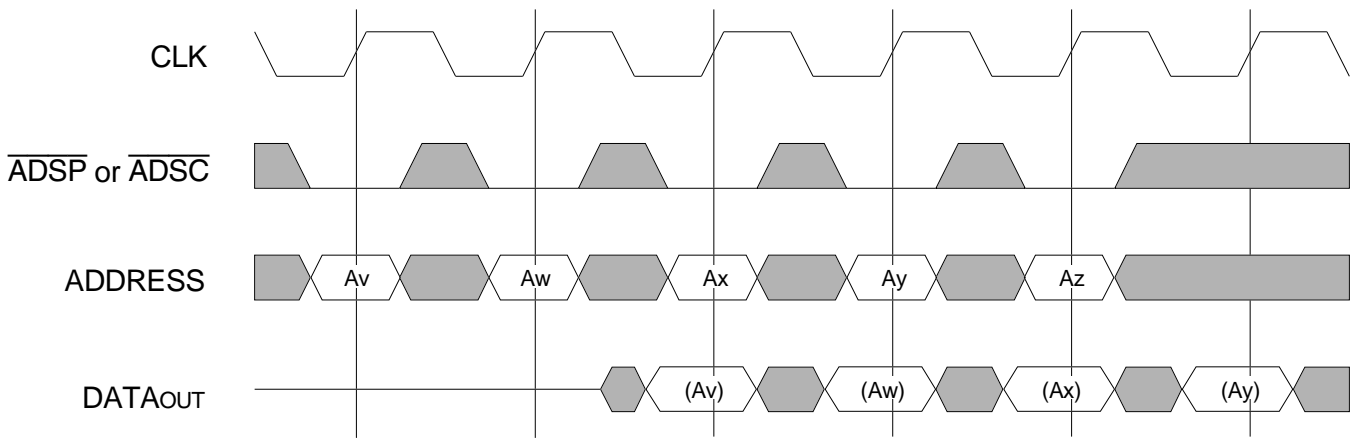


3104.drw 10

NOTES:

1. Device must power up in deselected Mode.
2. LBO input is Don't Care for this cycle.
3. It is not necessary to retain the state of the input registers throughout the Power-down cycle.
4. CS0 limiting transitions are identical but inverted to the CE and CS1 signals. For example, when \overline{CE} and $\overline{CS1}$ are LOW on this waveform, CS0 is HIGH.

Non-Burst Read Cycle Timing Waveform^(1,2,3,4)

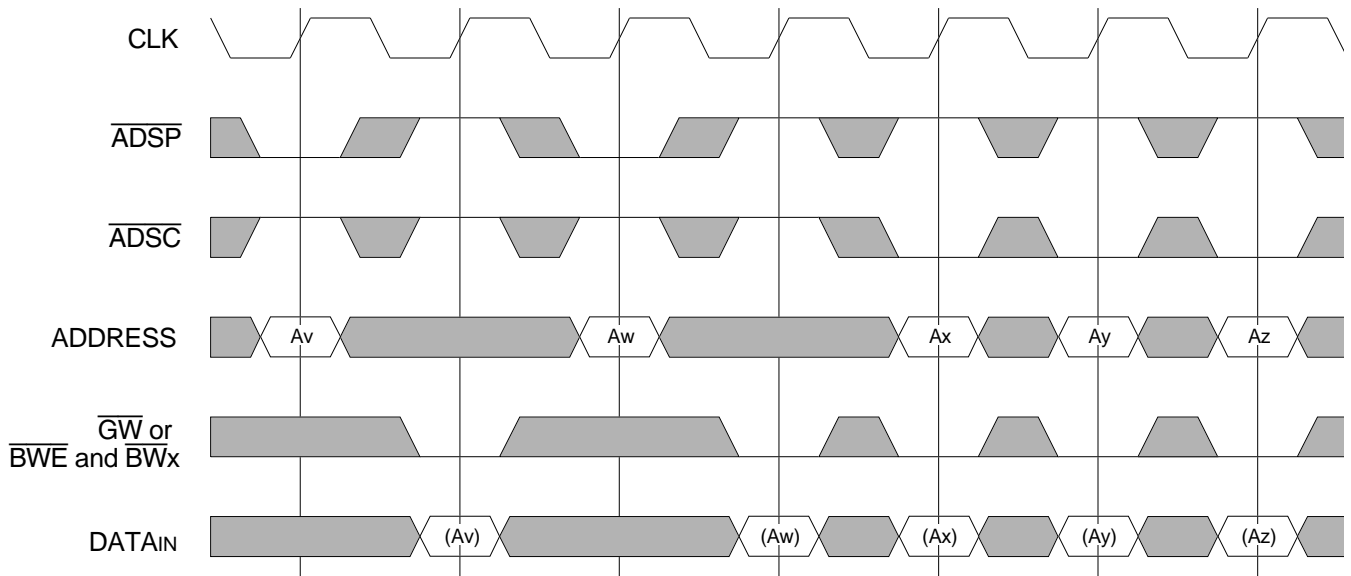


3104 drw 11

NOTES:

1. \overline{ZZ} , \overline{CE} , $\overline{CS_1}$, and \overline{OE} are LOW for this cycle.
2. \overline{ADV} , \overline{GW} , \overline{BWE} , \overline{BWx} , and $\overline{CS_0}$ are HIGH for this cycle.
3. (Ax) represents the data for address Ax, etc.
4. For read cycles, \overline{ADSP} and \overline{ADSC} function identically and are therefore interchangeable.

Non-Burst Write Cycle Timing Waveform^(1,2,3,4)

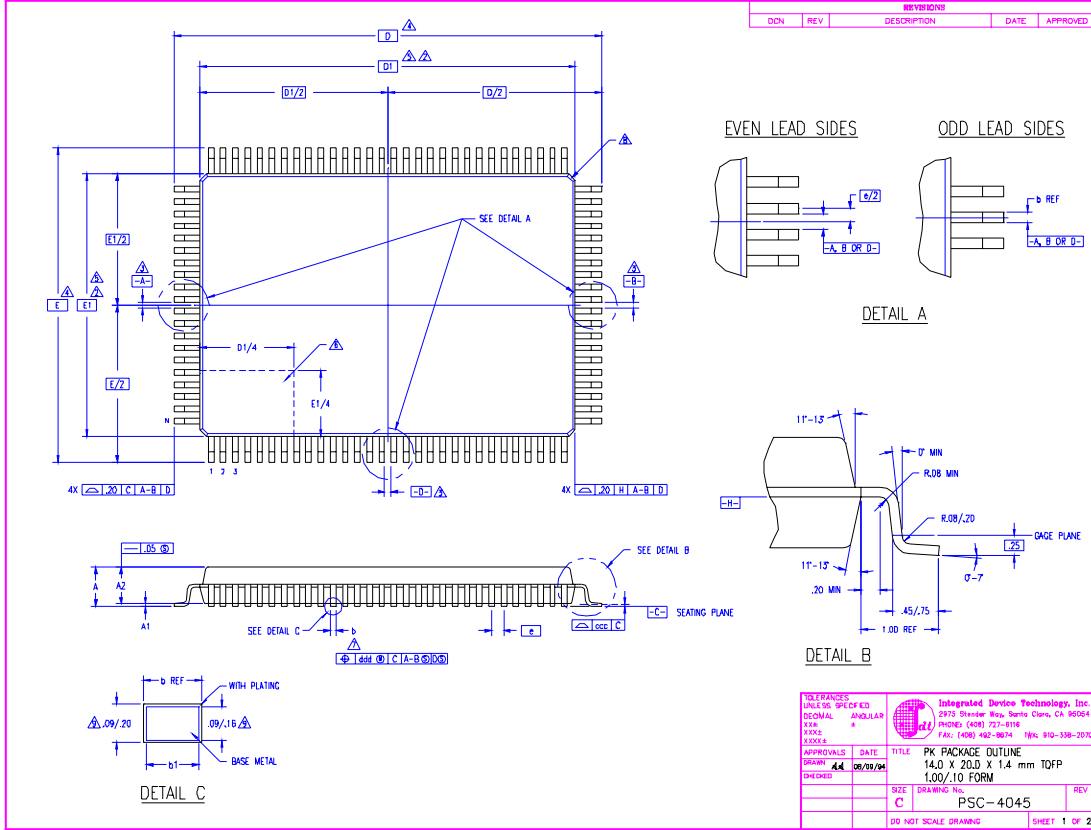


3104 drw 12

NOTES:

1. \overline{ZZ} , \overline{CE} and $\overline{CS_1}$ are LOW for this cycle.
2. \overline{ADV} , \overline{OE} and $\overline{CS_0}$ are HIGH for this cycle.
3. (Ax) represents the data for address Ax, etc.
4. For write cycles, \overline{ADSP} and \overline{ADSC} have different limitations.

100-pin Thin Plastic Quad Flatpack (TQFP) Package Diagram Outline



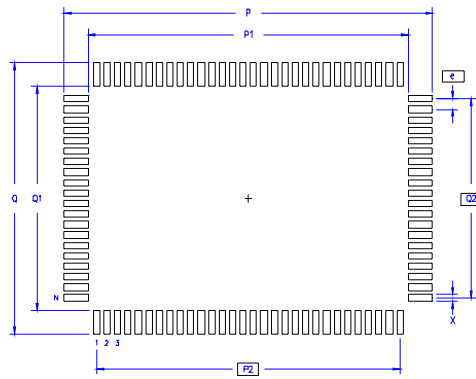
| SYMBOL | JEDEC VARIATION | | | UNIT |
|--------|-----------------|------|------|------|
| | MIN | NOM | MAX | |
| A | - | - | 1.60 | |
| A1 | .05 | .10 | .16 | |
| A2 | 1.35 | 1.40 | 1.45 | |
| D | 22.00 BSC | | | 4 |
| D1 | 20.00 BSC | | | 5,2 |
| E | 16.00 BSC | | | 4 |
| E1 | 14.00 BSC | | | 5,2 |
| N | 100 | | | |
| ND | 30 | | | |
| NE | 20 | | | |
| e | .65 BSC | | | |
| b | .22 | .32 | .38 | 7 |
| b1 | .22 | .30 | .33 | |
| ccc | - | - | .10 | |
| ddd | - | - | .13 | |

NOTES:

- 1 ALL DIMENSIONING AND TOLERANCING CONFORM TO ANSI Y14.5M-1982
- ⚠ TOP PACKAGE MAY BE SMALLER THAN BOTTOM PACKAGE BY .15 mm
- ⚠ DATUMS [A-B] AND [-D-] TO BE DETERMINED AT DATUM PLANE [-H-]
- ⚠ DIMENSIONS D AND E ARE TO BE DETERMINED AT SEATING PLANE [-C-]
- ⚠ DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION, ALLOWABLE MOLD PROTRUSION IS .25 mm PER SIDE, D1 AND E1 ARE MAXIMUM BODY SIZE DIMENSIONS INCLUDING MOLD MISMATCH
- ⚠ DETAILS OF PIN 1 IDENTIFIER IS OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED
- ⚠ DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION, ALLOWABLE DAMBAR PROTRUSION IS .08 mm IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION, DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT.
- ⚠ EXACT SHAPE OF EACH CORNER IS OPTIONAL
- ⚠ THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .10 AND .25 mm FROM THE LEAD TIP
- 10 ALL DIMENSIONS ARE IN MILLIMETERS
- 11 THIS OUTLINE CONFORMS TO JEDEC PUBLICATION 95 REGISTRATION MQ-136, VARIATION DJ AND BX

| REVISIONS | | | | |
|-----------|-----|-------------|------|----------|
| DCN | REV | DESCRIPTION | DATE | APPROVED |
| | | | | |

LAND PATTERN DIMENSIONS



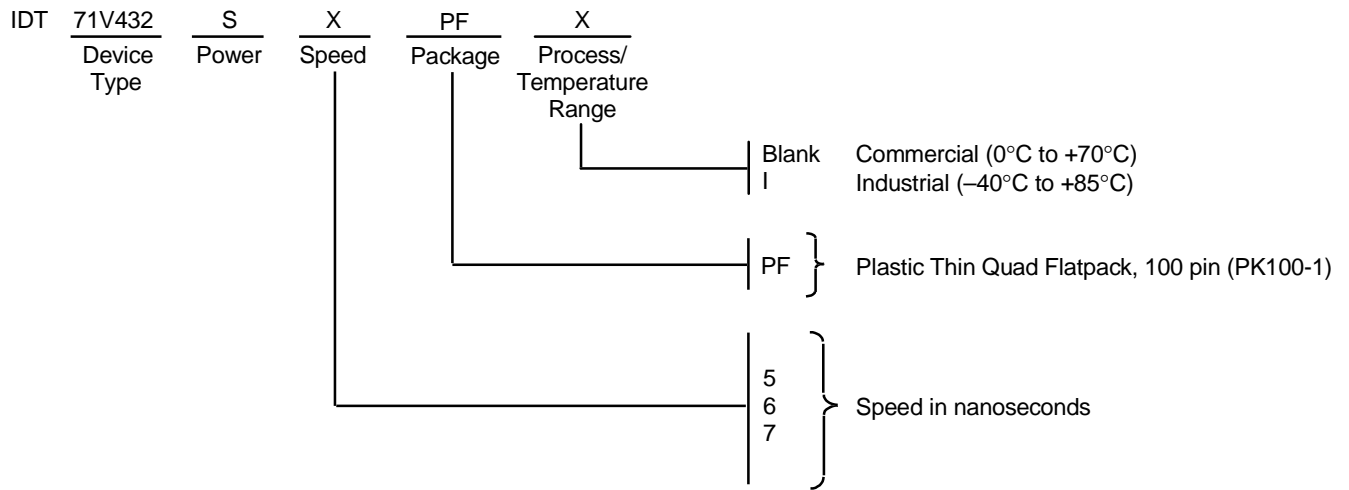
| | MIN | MAX |
|----|-----------|-------|
| P | 22.80 | 23.00 |
| P1 | 19.80 | 20.00 |
| P2 | 18.85 BSC | |
| Q | 16.80 | 17.00 |
| Q1 | 13.80 | 14.00 |
| Q2 | 12.35 BSC | |
| X | .30 | .50 |
| e | .65 BSC | |
| N | 100 | |

| TOLERANCES UNLESS SPECIFIED | | | | |
|-----------------------------|---------|-----|-----|-----|
| DECIMAL | ANGULAR | XXX | XXX | XXX |
| .05 | ° | | | |

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 PHONE: (408) 727-8100
 FAX: (408) 402-8674 TEL: 910-338-2070

| APPROVALS | DATE | TITLE | REV |
|----------------|----------|-----------------------------|--------------|
| DRW: AA | 08/29/94 | PK PACKAGE OUTLINE | |
| CHEK: C | | 14.0 X 20.0 X 1.4 mm TQFP | |
| | | 1.00/.10 FORM | |
| | | SIZE: C | |
| | | DRAWING NO: PSC-4045 | |
| | | DO NOT SCALE DRAWING | SHEET 2 OF 2 |

Ordering Information



| PART NUMBER | SPEED IN MEGAHERTZ | t _{CD} PARAMETER | CLOCK CYCLE TIME |
|-------------|--------------------|---------------------------|------------------|
| 71V432S5PF | 100 MHz | 5 ns | 10 ns |
| 71V432S6PF | 83 MHz | 6 ns | 12 ns |
| 71V432S7PF | 66 MHz | 7 ns | 15 ns |

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Datasheet Document History

| | | |
|----------|--------------------|--------------------------------------------------------------------------------|
| 9/10/99 | | Updated to new format |
| | Pg. 3-5 | Adjusted page layout, added extra page |
| | Pg. 5 | Added notes to pin configuration |
| | Pg. 11-14 | Revised notes |
| | Pg. 17 | Added Datasheet Document History |
| 03/09/00 | Pg. 1, 4, 8, 9, 16 | Added Industrial temperature range offerings |
| 04/04/00 | Pg. 16 | Added 100pinTQFP package Diagram Outline |
| 08/09/00 | | Not recommended for new designs |
| 08/17/01 | | Removed "Not recommended for new designs" from the background on the datasheet |


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